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## REVISION HISTORY

### 1/2020—Rev. C to Rev. D

Change to Features Section .....	1
Changes to Leakage Currents Parameter, Table 1 .....	3
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### 3/2016—Rev. B to Rev. C

Changed CP-16-13 to CP-16-26 .....	Throughout
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Updated Outline Dimensions .....	15
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### 3/2011—Rev. A to Rev. B

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Updated Outline Dimensions .....	15
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### 3/2009—Rev. 0 to Rev. A

Changes to Power Requirements, IDD, Digital Inputs = 5 V Parameter, Table 1 .....	3
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### 5/2008—Revision 0: Initial Version

## SPECIFICATIONS

## ±15 V DUAL SUPPLY

$V_{DD} = 15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ , GND = 0 V, unless otherwise noted.

Table 1.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
<b>ANALOG SWITCH</b>					
Analog Signal Range			$V_{DD}$ to $V_{SS}$	V	
On Resistance, $R_{ON}$	1.5			$\Omega$ typ	$V_S = \pm 10\text{ V}$ , $I_S = -10\text{ mA}$ ; see Figure 23
	1.8	2.3	2.6	$\Omega$ max	$V_{DD} = +13.5\text{ V}$ , $V_{SS} = -13.5\text{ V}$
On-Resistance Match Between Channels, $\Delta R_{ON}$	0.1			$\Omega$ typ	$V_S = \pm 10\text{ V}$ , $I_S = -10\text{ mA}$
	0.18	0.19	0.21	$\Omega$ max	
On-Resistance Flatness, $R_{FLAT(ON)}$	0.3			$\Omega$ typ	$V_S = \pm 10\text{ V}$ , $I_S = -10\text{ mA}$
	0.36	0.4	0.45	$\Omega$ max	
<b>LEAKAGE CURRENTS</b>					
Source Off Leakage, $I_S$ (Off)	±0.03			nA typ	$V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$
	±0.55	±2	±12.5	nA max	$V_S = \pm 10\text{ V}$ , $V_D = \mp 10\text{ V}$ ; see Figure 24
ADG1411WBCPZ-REEL Only	±3		±40	nA max	
Drain Off Leakage, $I_D$ (Off)	±0.03			nA typ	$V_S = \pm 10\text{ V}$ , $V_D = \mp 10\text{ V}$ ; see Figure 24
	±0.55	±2	±12.5	nA max	
ADG1411WBCPZ-REEL Only	±3		±40	nA max	
Channel On Leakage, $I_D$ , $I_S$ (On)	±0.15			nA typ	$V_S = V_D = \pm 10\text{ V}$ ; see Figure 25
	±2	±4	±30	nA max	
ADG1411WBCPZ-REEL Only	±3		±40	nA max	
<b>DIGITAL INPUTS</b>					
Input High Voltage, $V_{INH}$			2.0	V min	
Input Low Voltage, $V_{INL}$			0.8	V max	
Input Current, $I_{INL}$ or $I_{INH}$	0.005		±0.1	$\mu\text{A}$ typ	$V_{IN} = V_{GND}$ or $V_{DD}$
				$\mu\text{A}$ max	
Digital Input Capacitance, $C_{IN}$	3.5			pF typ	
<b>DYNAMIC CHARACTERISTICS<sup>1</sup></b>					
$t_{ON}$	100			ns typ	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$
	150	170	190	ns max	$V_S = 10\text{ V}$ ; see Figure 30
$t_{OFF}$	90			ns typ	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$
	120	140	160	ns max	$V_S = 10\text{ V}$ ; see Figure 30
Break-Before-Make Time Delay, $t_D$ (ADG1413 Only)	25			ns typ	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$
			10	ns min	$V_{S1} = V_{S2} = 10\text{ V}$ ; see Figure 31
Charge Injection, $Q_{INJ}$	−20			pC typ	$V_S = 0\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 32
Off Isolation	−80			dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 100\text{ kHz}$ ; see Figure 26
Channel-to-Channel Crosstalk	−100			dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 27
Total Harmonic Distortion + Noise	0.014			% typ	$R_L = 110\ \Omega$ , 15 V p-p, $f = 20\text{ Hz}$ to $20\text{ kHz}$ ; see Figure 29
−3 dB Bandwidth	170			MHz typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 28
Insertion Loss	−0.35			dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 28
$C_S$ (Off)	23			pF typ	$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$
$C_D$ (Off)	23			pF typ	$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$
$C_D$ , $C_S$ (On)	116			pF typ	$V_S = 0\text{ V}$ , $f = 1\text{ MHz}$
<b>POWER REQUIREMENTS</b>					
$I_{DD}$	0.001			$\mu\text{A}$ typ	$V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$
			1	$\mu\text{A}$ max	Digital inputs = 0 V or $V_{DD}$
$I_{DD}$	220			$\mu\text{A}$ typ	Digital inputs = 5 V
			380	$\mu\text{A}$ max	
$I_{SS}$	0.001			$\mu\text{A}$ typ	Digital inputs = 0 V or $V_{DD}$
			1	$\mu\text{A}$ max	
$V_{DD}/V_{SS}$			±4.5/±16.5	V min/V max	GND = 0 V

<sup>1</sup> Guaranteed by design; not subject to production test.

**+12 V SINGLE SUPPLY**

$V_{DD} = 12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

**Table 2.**

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V <sub>DD</sub>	V	
On Resistance, R <sub>ON</sub>	2.8 3.5	4.3	4.8	Ω typ Ω max	V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = −10 mA; see Figure 23 V <sub>DD</sub> = 10.8 V, V <sub>SS</sub> = 0 V
On-Resistance Match Between Channels, ΔR <sub>ON</sub>	0.13			Ω typ	V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = −10 mA
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	0.21	0.23	0.25	Ω max	V <sub>S</sub> = 0 V to 10 V, I <sub>S</sub> = −10 mA
	0.6			Ω typ	
	1.1	1.2	1.3	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I <sub>S</sub> (Off)	±0.02 ±0.55	±2	±12.5 ±40	nA typ nA max	V <sub>DD</sub> = 10.8 V, V <sub>SS</sub> = 0 V V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/0 V; see Figure 24
ADG1411WBCPZ-REEL Only	±3			nA max	
Drain Off Leakage, I <sub>D</sub> (Off)	±0.02 ±0.55	±2	±12.5 ±40	nA typ nA max	V <sub>S</sub> = 1 V/10 V, V <sub>D</sub> = 10 V/0 V; see Figure 24
ADG1411WBCPZ-REEL Only	±3			nA max	
Channel On Leakage, I <sub>D</sub> , I <sub>S</sub> (On)	±0.15 ±1.5	±4	±30 ±40	nA typ nA max	V <sub>S</sub> = V <sub>D</sub> = 1 V/10 V; see Figure 25
ADG1411WBCPZ-REEL Only	±3			nA max	
DIGITAL INPUTS					
Input High Voltage, V <sub>INH</sub>			2.0	V min	V <sub>IN</sub> = V <sub>GND</sub> or V <sub>DD</sub>
Input Low Voltage, V <sub>INL</sub>			0.8	V max	
Input Current, I <sub>INL</sub> or I <sub>INH</sub>	0.001		±0.1	μA typ	
				μA max	
Digital Input Capacitance, C <sub>IN</sub>	3.5			pF typ	
DYNAMIC CHARACTERISTICS <sup>1</sup>					
t <sub>ON</sub>	170 250	295	330	ns typ ns max	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF V <sub>S</sub> = 8 V; see Figure 30
t <sub>OFF</sub>	75 135			165	190
Break-Before-Make Time Delay, t <sub>D</sub> (ADG1413 Only)	100		40		
Charge Injection, Q <sub>INJ</sub>	30			ns min	V <sub>S1</sub> = V <sub>S2</sub> = 8 V; see Figure 31
Off Isolation	−80		pC typ	V <sub>S</sub> = 6 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF; see Figure 32	
Channel-to-Channel Crosstalk	−100		dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 100 kHz; see Figure 26	
−3 dB Bandwidth	130		dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 27	
Insertion Loss	−0.5		MHz typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 28	
C <sub>S</sub> (Off)	38		dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 28	
C <sub>D</sub> (Off)	40		pF typ	V <sub>S</sub> = 6 V, f = 1 MHz	
C <sub>D</sub> , C <sub>S</sub> (On)	104		pF typ	V <sub>S</sub> = 6 V, f = 1 MHz	
POWER REQUIREMENTS					
I <sub>DD</sub>	0.001		1	μA typ μA max	V <sub>DD</sub> = 13.2 V Digital inputs = 0 V or V <sub>DD</sub>
	220			μA typ μA max	Digital inputs = 5 V
V <sub>DD</sub>			380 5/16.5	V min/V max	GND = 0 V, V <sub>SS</sub> = 0 V

<sup>1</sup> Guaranteed by design; not subject to production test.

**±5 V DUAL SUPPLY**

$V_{DD} = 5\text{ V} \pm 10\%$ ,  $V_{SS} = -5\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

**Table 3.**

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V <sub>DD</sub> to V <sub>SS</sub>	V	
On Resistance, R <sub>ON</sub>	3.3			Ω typ	V <sub>S</sub> = ±4.5 V, I <sub>S</sub> = −10 mA; see Figure 23
	4	4.9	5.4	Ω max	V <sub>DD</sub> = +4.5 V, V <sub>SS</sub> = −4.5 V
On-Resistance Match Between Channels, ΔR <sub>ON</sub>	0.13			Ω typ	V <sub>S</sub> = ±4.5 V, I <sub>S</sub> = −10 mA
	0.22	0.23	0.25	Ω max	
On-Resistance Flatness, R <sub>FLAT(ON)</sub>	0.9			Ω typ	V <sub>S</sub> = ±4.5 V; I <sub>S</sub> = −10 mA
	1.1	1.24	1.31	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I <sub>S</sub> (Off)	±0.03			nA typ	V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = −5.5 V
	±0.55	±2	±12.5	nA max	V <sub>S</sub> = ±4.5 V, V <sub>D</sub> = ∓4.5 V; see Figure 24
ADG1411WBCPZ-REEL Only	±3		±40	nA max	
Drain Off Leakage, I <sub>D</sub> (Off)	±0.03			nA typ	V <sub>S</sub> = ±4.5 V, V <sub>D</sub> = ∓4.5 V; see Figure 24
	±0.55	±2	±12.5	nA max	
ADG1411WBCPZ-REEL Only	±3		±40	nA max	
Channel On Leakage, I <sub>D</sub> , I <sub>S</sub> (On)	±0.05			nA typ	V <sub>S</sub> = V <sub>D</sub> = ±4.5 V; see Figure 25
	±1.0	±4	±30	nA max	
ADG1411WBCPZ-REEL Only1	±3		±40	nA max	
DIGITAL INPUTS					
Input High Voltage, V <sub>INH</sub>			2.0	V min	
Input Low Voltage, V <sub>INL</sub>			0.8	V max	
Input Current, I <sub>INL</sub> or I <sub>INH</sub>	0.001		±0.1	μA typ	V <sub>IN</sub> = V <sub>GND</sub> or V <sub>DD</sub>
				μA max	
Digital Input Capacitance, C <sub>IN</sub>	3.5			pF typ	
DYNAMIC CHARACTERISTICS <sup>1</sup>					
t <sub>ON</sub>	275			ns typ	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF
	400	465	510	ns max	V <sub>S</sub> = 3 V; see Figure 30
t <sub>OFF</sub>	175			ns typ	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF
	290	320	380	ns max	V <sub>S</sub> = 3 V; see Figure 30
Break-Before-Make Time Delay, t <sub>D</sub> (ADG1413 Only)	100		50	ns typ	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF
Charge Injection, Q <sub>INJ</sub>	30			ns min	V <sub>S1</sub> = V <sub>S2</sub> = 3 V; see Figure 31
Off Isolation	−80			pC typ	V <sub>S</sub> = 0 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 1 nF; see Figure 32
Channel-to-Channel Crosstalk	−100			dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 100 kHz; see Figure 26
Total Harmonic Distortion + Noise	0.03			dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 27
				% typ	R <sub>L</sub> = 110 Ω, 5 V p-p, f = 20 Hz to 20 kHz; see Figure 29
−3 dB Bandwidth	130			MHz typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF; see Figure 28
Insertion Loss	−0.5			dB typ	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; see Figure 28
C <sub>S</sub> (Off)	32			pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
C <sub>D</sub> (Off)	33			pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
C <sub>D</sub> , C <sub>S</sub> (On)	116			pF typ	V <sub>S</sub> = 0 V, f = 1 MHz
POWER REQUIREMENTS					
I <sub>DD</sub>	0.001		1.0	μA typ	V <sub>DD</sub> = +5.5 V, V <sub>SS</sub> = −5.5 V
				μA max	Digital inputs = 0 V or V <sub>DD</sub>
I <sub>SS</sub>	0.001		1.0	μA typ	Digital inputs = 0 V or V <sub>DD</sub>
				μA max	
V <sub>DD</sub> /V <sub>SS</sub>			±4.5/±16.5	V min/V max	GND = 0 V

<sup>1</sup> Guaranteed by design; not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 4.**

Parameter	Rating
$V_{DD}$ to $V_{SS}$	35 V
$V_{DD}$ to GND	−0.3 V to +25 V
$V_{SS}$ to GND	+0.3 V to −25 V
Analog Inputs <sup>1</sup>	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Digital Inputs <sup>1</sup>	GND − 0.3 V to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Peak Current, Sx or Dx Pins	500 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous Current per Channel at $25^\circ\text{C}$	
16-Lead TSSOP	190 mA
16-Lead LFCSP	250 mA
Continuous Current per Channel at $125^\circ\text{C}$	
16-Lead TSSOP	90 mA
16-Lead LFCSP	100 mA
Operating Temperature Range	
Automotive (Y Version)	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
$\theta_{JA}$ Thermal Impedance	
16-Lead TSSOP (4-Layer Board)	112°C/W
16-Lead LFCSP	30.4°C/W
Reflow Soldering Peak Temperature, Pb Free	260(+0/−5)°C

<sup>1</sup> Overvoltages at the INx, Sx, and Dx pins are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating may be applied at any one time.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

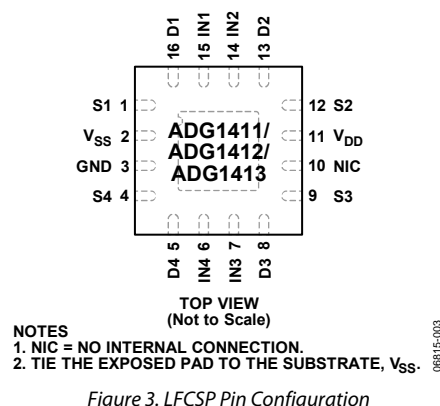
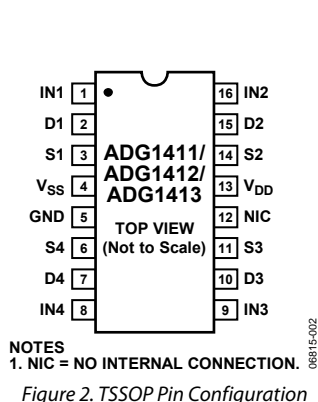


Table 5. Pin Function Descriptions

Pin No.		Mnemonic	Description
TSSOP	LFCSP		
1	15	IN1	Logic Control Input.
2	16	D1	Drain Terminal. This pin can be an input or output.
3	1	S1	Source Terminal. This pin can be an input or output.
4	2	$V_{SS}$	Most Negative Power Supply Potential.
5	3	GND	Ground (0 V) Reference.
6	4	S4	Source Terminal. This pin can be an input or output.
7	5	D4	Drain Terminal. This pin can be an input or output.
8	6	IN4	Logic Control Input.
9	7	IN3	Logic Control Input.
10	8	D3	Drain Terminal. This pin can be an input or output.
11	9	S3	Source Terminal. This pin can be an input or output.
12	10	NIC	No Internal Connection.
13	11	$V_{DD}$	Most Positive Power Supply Potential.
14	12	S2	Source Terminal. This pin can be an input or output.
15	13	D2	Drain Terminal. This pin can be an input or output.
16	14	IN2	Logic Control Input.
N/A <sup>1</sup>	0	EPAD	Exposed Pad. Tie the exposed pad to the substrate, $V_{SS}$ .

<sup>1</sup> N/A means not applicable.

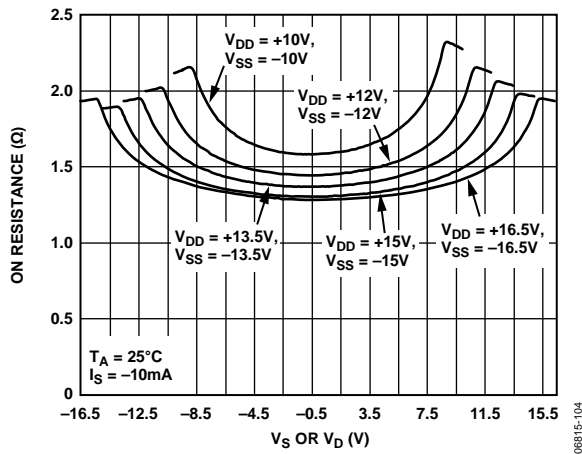
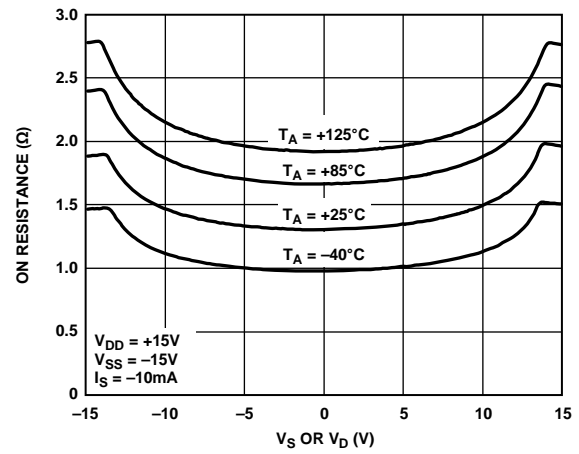
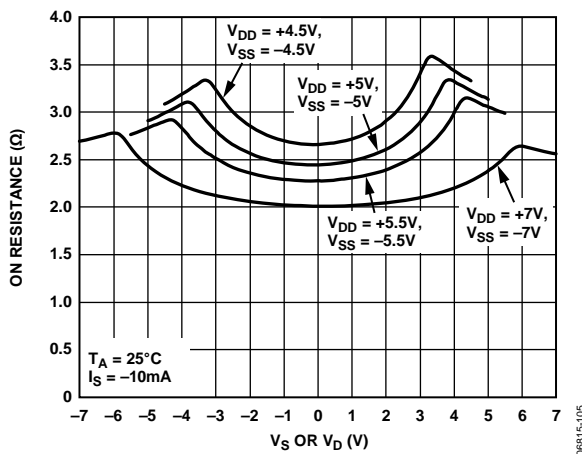
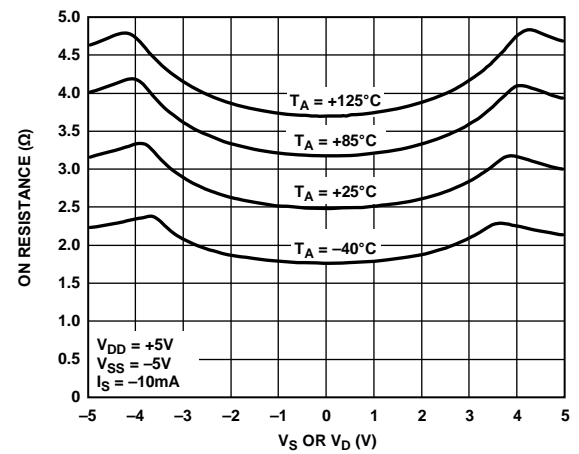
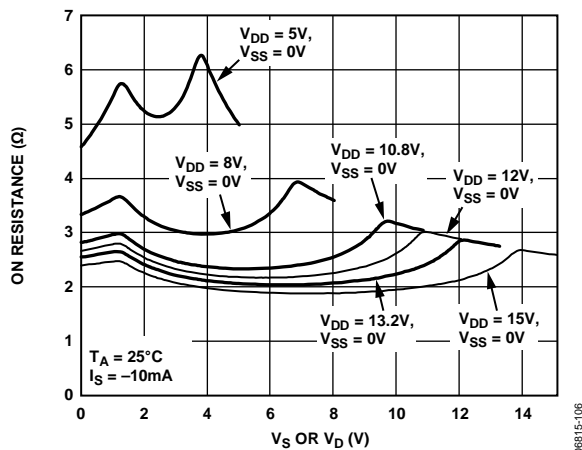
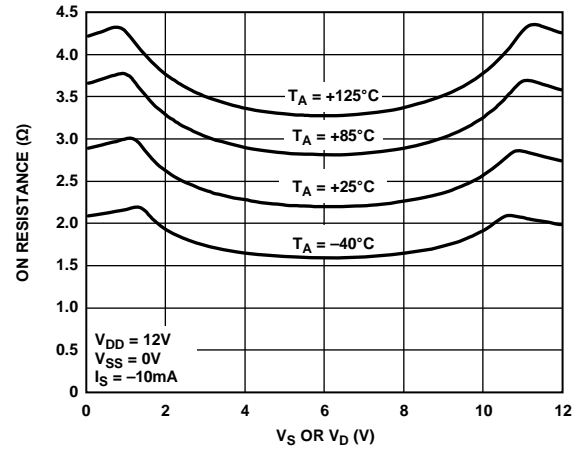
Table 6. ADG1411/ADG1412 Truth Table

ADG1411 INx	ADG1412 INx	Switch Condition
0	1	On
1	0	Off

Table 7. ADG1413 Truth Table

ADG1413 INx	S1, S4	S2, S3
0	Off	On
1	On	Off

## TYPICAL PERFORMANCE CHARACTERISTICS

Figure 4. On Resistance vs.  $V_D$  or  $V_S$ , Dual SupplyFigure 7. On Resistance vs.  $V_D$  or  $V_S$  for Different Temperatures,  $\pm 15$  V Dual SupplyFigure 5. On Resistance vs.  $V_D$  or  $V_S$ , Dual SupplyFigure 8. On Resistance vs.  $V_D$  or  $V_S$  for Different Temperatures,  $\pm 5$  V Dual SupplyFigure 6. On Resistance vs.  $V_D$  or  $V_S$ , Single SupplyFigure 9. On Resistance vs.  $V_D$  or  $V_S$  for Different Temperatures, +12 V Single Supply

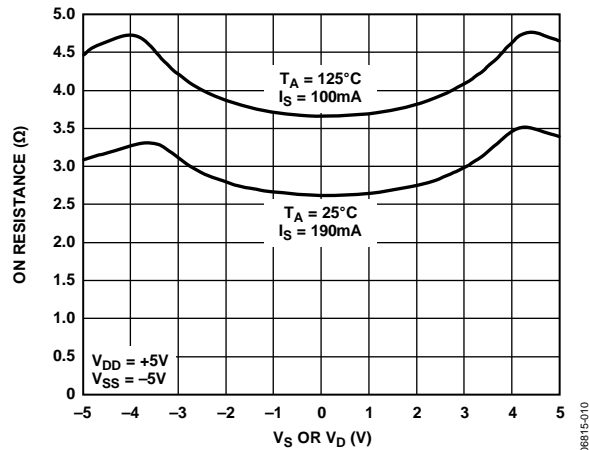


Figure 10. On Resistance vs.  $V_D$  or  $V_S$  for Different Current Levels,  $\pm 5$  V Dual Supply

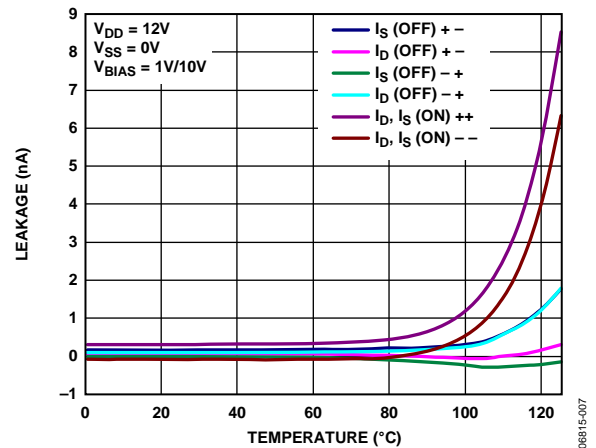


Figure 13. Leakage Currents vs. Temperature, +12 V Single Supply

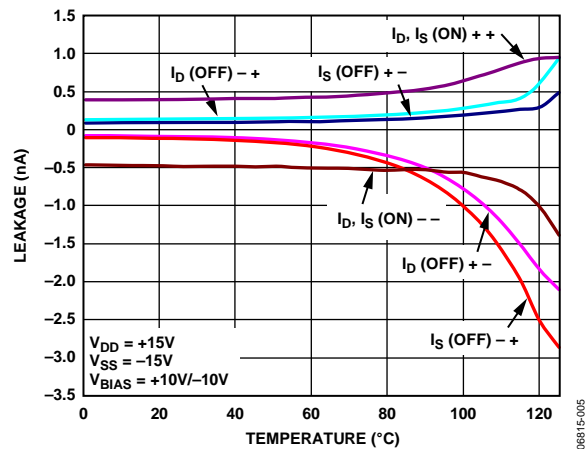


Figure 11. Leakage Currents vs. Temperature,  $\pm 15$  V Dual Supply

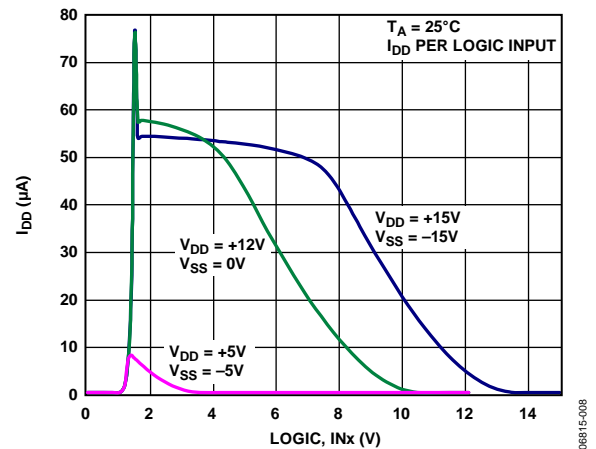


Figure 14.  $I_{DD}$  vs. Logic Level

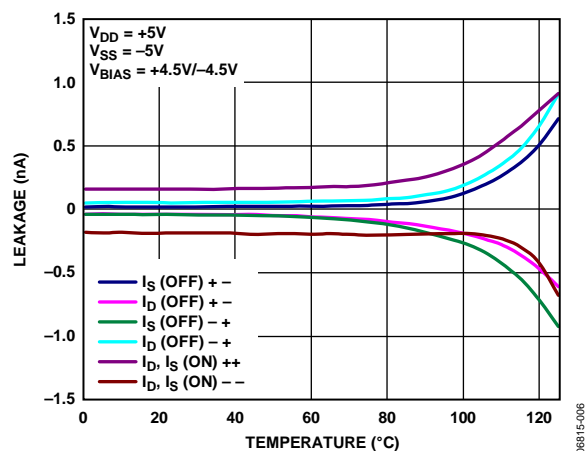


Figure 12. Leakage Currents vs. Temperature,  $\pm 5$  V Dual Supply

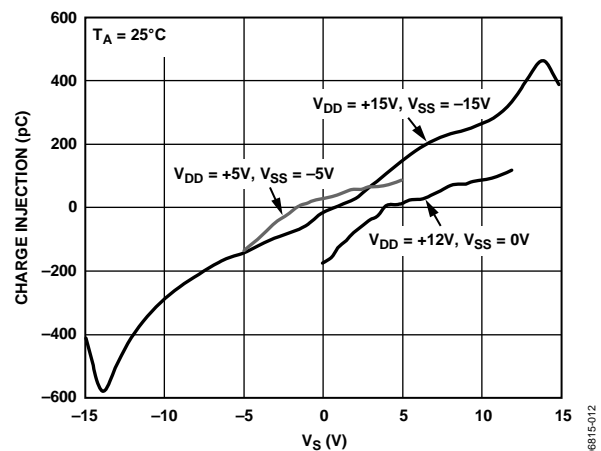


Figure 15. Charge Injection vs. Source Voltage



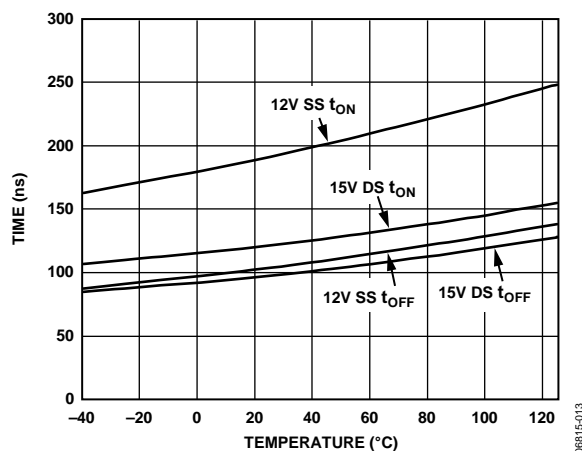


Figure 16.  $t_{ON}/t_{OFF}$  Times vs. Temperature for Single Supply (SS) and Dual Supply (DS)

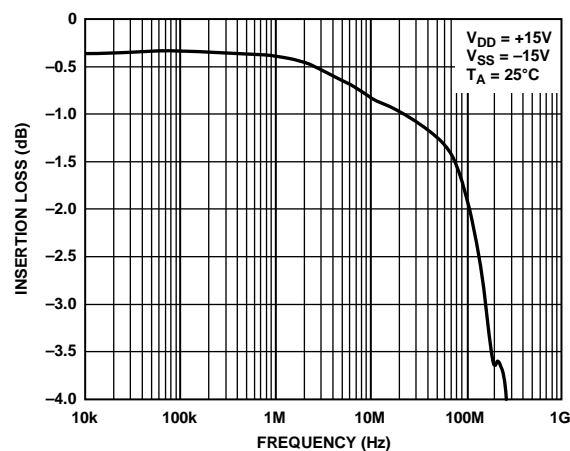


Figure 19. On Response vs. Frequency,  $\pm 15$  V Dual Supply

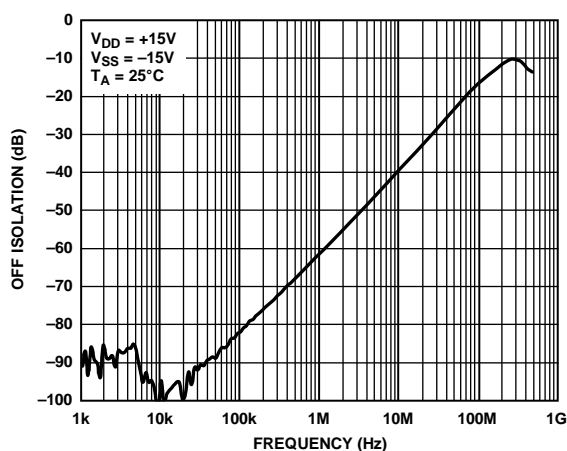


Figure 17. Off Isolation vs. Frequency,  $\pm 15$  V Dual Supply

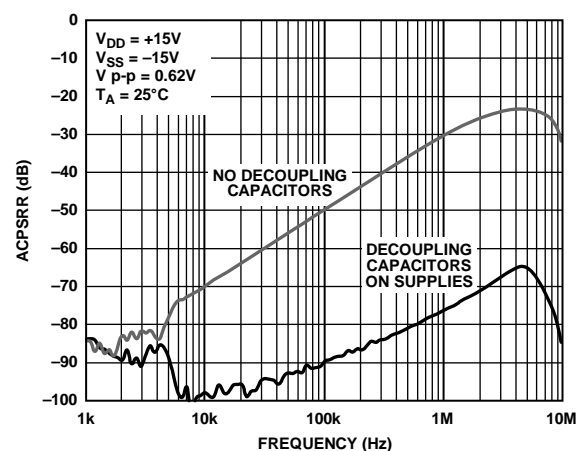


Figure 20. ACPSRR vs. Frequency,  $\pm 15$  V Dual Supply

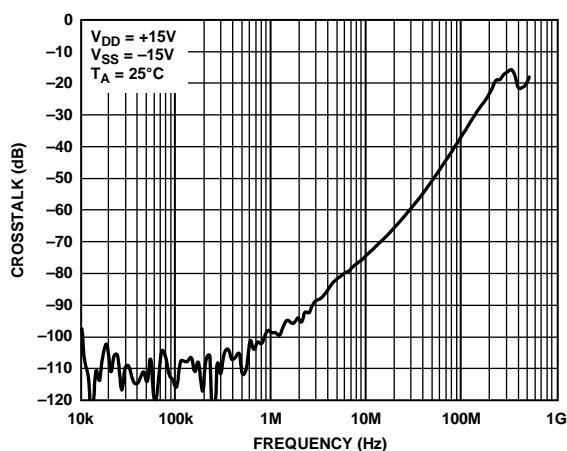


Figure 18. Crosstalk vs. Frequency,  $\pm 15$  V Dual Supply

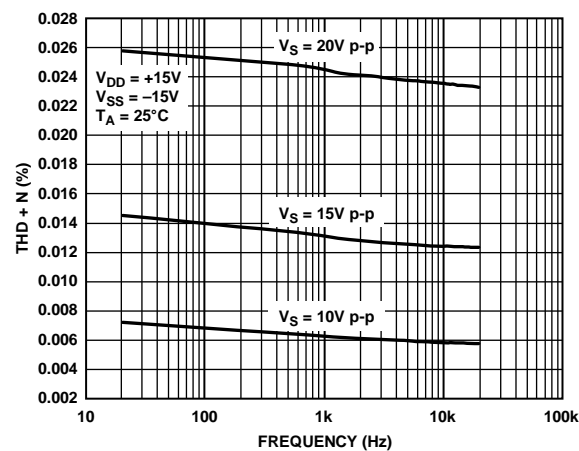


Figure 21. THD + N vs. Frequency,  $\pm 15$  V Dual Supply

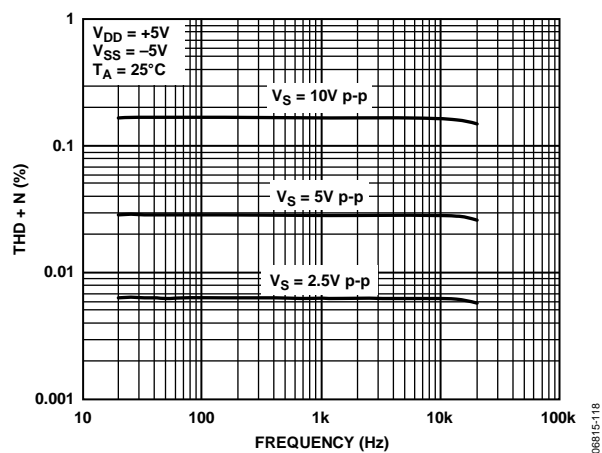


Figure 22. THD + N vs. Frequency,  
 $\pm 5V$  Dual Supply

08815-118

## TERMINOLOGY

### **I<sub>DD</sub>**

The positive supply current.

### **I<sub>SS</sub>**

The negative supply current.

### **V<sub>D</sub>, V<sub>S</sub>**

The analog voltage on Terminal D and Terminal S.

### **R<sub>ON</sub>**

The ohmic resistance between Terminal D and Terminal S.

### **R<sub>FLAT(ON)</sub>**

Flatness is defined as the difference between the maximum and minimum value of on resistance measured over the specified analog signal range.

### **I<sub>S</sub> (Off)**

The source leakage current with the switch off.

### **I<sub>D</sub> (Off)**

The drain leakage current with the switch off.

### **I<sub>D</sub>, I<sub>S</sub> (On)**

The channel leakage current with the switch on.

### **V<sub>INL</sub>**

The maximum input voltage for Logic 0.

### **V<sub>INH</sub>**

The minimum input voltage for Logic 1.

### **I<sub>INL</sub>, I<sub>INH</sub>**

The input current of the digital input when high or when low.

### **C<sub>S</sub> (Off)**

The off switch source capacitance, which is measured with reference to ground.

### **C<sub>D</sub> (Off)**

The off switch drain capacitance, which is measured with reference to ground.

### **C<sub>D</sub>, C<sub>S</sub> (On)**

The on switch capacitance, which is measured with reference to ground.

### **C<sub>IN</sub>**

The digital input capacitance.

### **t<sub>ON</sub>**

The delay between applying the digital control input and the output switching on. See Figure 30.

### **t<sub>OFF</sub>**

The delay between applying the digital control input and the output switching off.

### **Charge Injection**

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

### **Off Isolation**

A measure of unwanted signal coupling through an off switch.

### **Crosstalk**

A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

### **Bandwidth**

The frequency at which the output is attenuated by 3 dB.

### **On Response**

The frequency response of the on switch.

### **Insertion Loss**

The loss due to the on resistance of the switch.

### **Total Harmonic Distortion + Noise (THD + N)**

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

### **AC Power Supply Rejection Ratio (ACPSRR)**

A measure of the ability of the device to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of the signal on the output to the amplitude of the modulation is the ACPSRR.

## TEST CIRCUITS

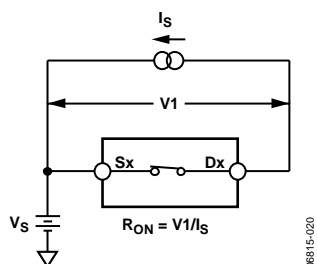


Figure 23. On Resistance

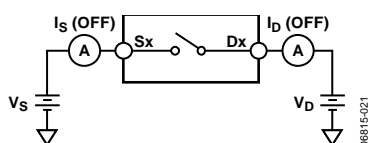


Figure 24. Off Leakage

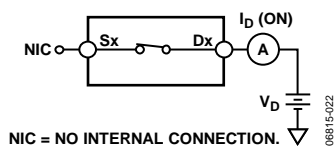


Figure 25. On Leakage

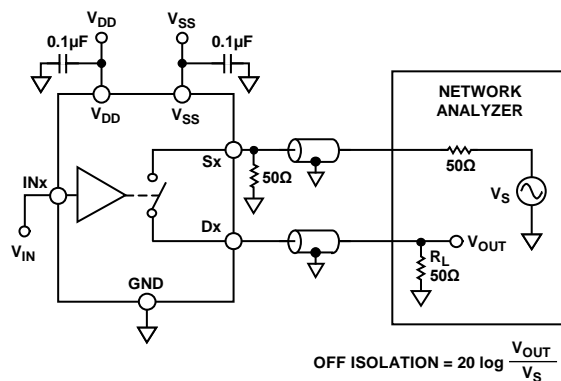


Figure 26. Off Isolation

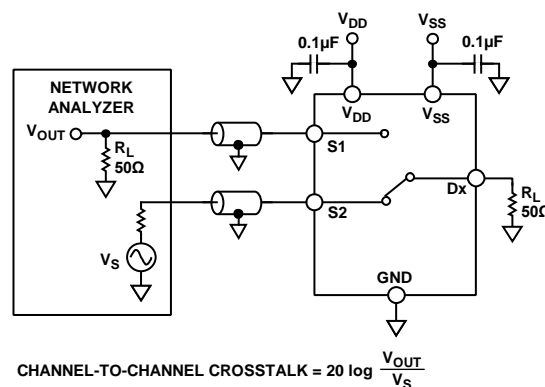


Figure 27. Channel-to-Channel Crosstalk

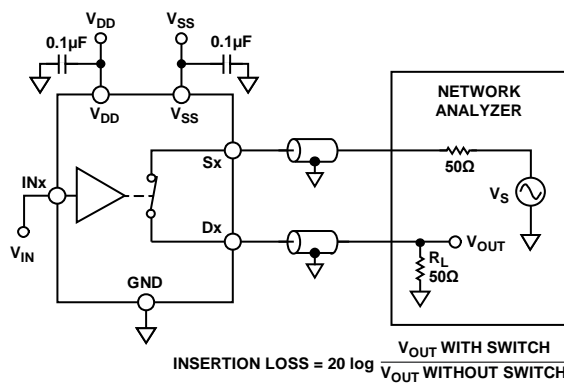


Figure 28. Bandwidth

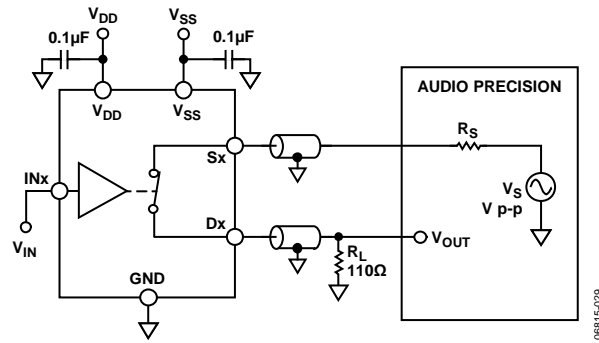


Figure 29. THD + Noise

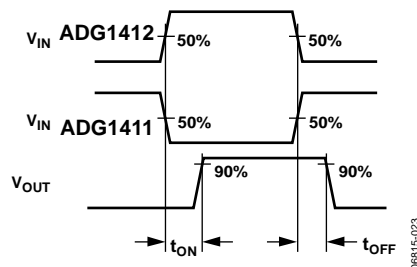
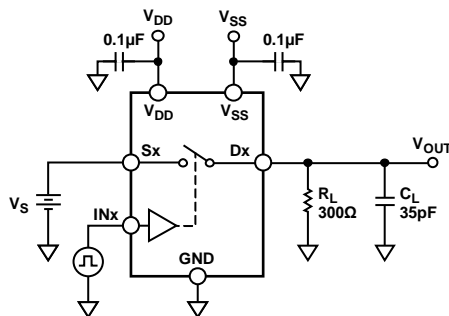


Figure 30. Switching Times

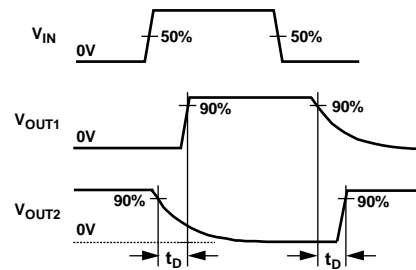
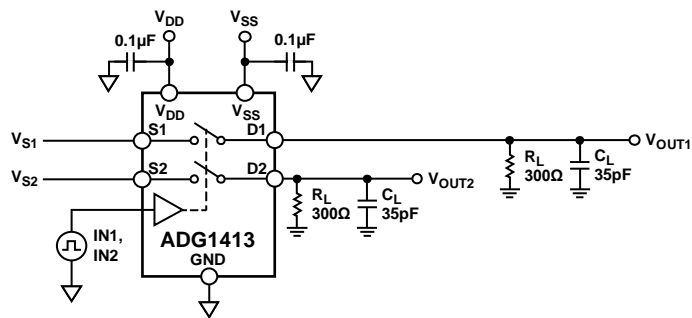


Figure 31. Break-Before-Make Time Delay

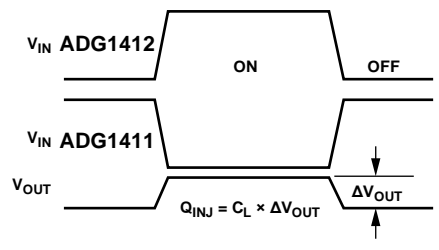
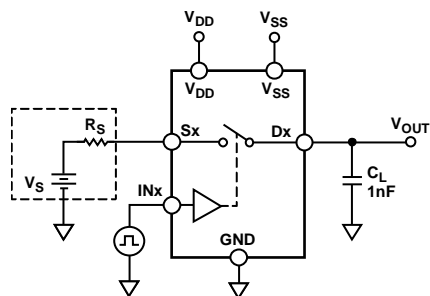


Figure 32. Charge Injection

## OUTLINE DIMENSIONS

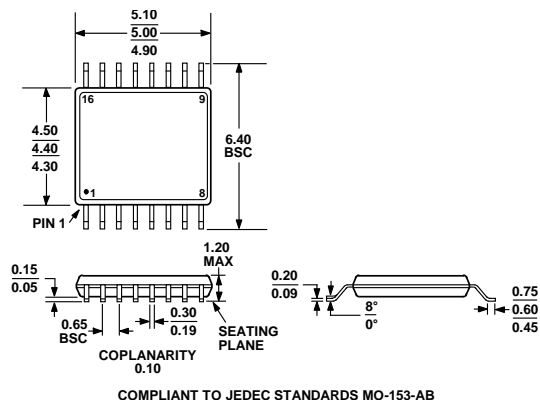


Figure 33. 16-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-16)  
Dimensions shown in millimeters

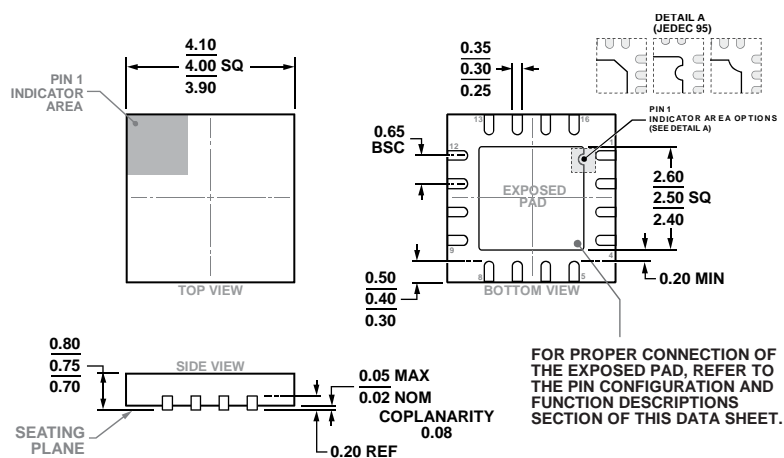


Figure 34. 16-Lead Lead Frame Chip Scale Package [LFCSP]  
4 mm × 4 mm Body and 0.75 mm Package Height  
(CP-16-26)  
Dimensions shown in millimeters

## ORDERING GUIDE

Model <sup>1,2</sup>	Temperature Range	Package Description	Package Option
ADG1411YRUZ	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1411YRUZ-REEL7	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1411YCPZ-REEL	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1411YCPZ-REEL7	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1411WBCPZ-REEL	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1412YRUZ	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1412YRUZ-REEL7	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1412YCPZ-REEL	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1412YCPZ-REEL7	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1413YRUZ	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1413YRUZ-REEL7	–40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1413YCPZ-REEL	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1413YCPZ-REEL7	–40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26

<sup>1</sup> Z = RoHS Compliant Part.<sup>2</sup> W = qualified for automotive applications.

## AUTOMOTIVE PRODUCTS

The **ADG1411W** model is available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that this automotive model may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade product shown is available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for this model.